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## High-fidelity entangling gate for double-quantum-dot spin qubits

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Electron spins in semiconductors are promising qubits because their long coherence times enable nearly  $10^9$  coherent quantum gate operations. However, developing a scalable high-fidelity two-qubit gate remains challenging. Here, we demonstrate an entangling gate between two double-quantum-dot spin qubits in GaAs by using a magnetic field gradient between the two dots in each qubit to suppress decoherence due to charge noise. When the magnetic gradient dominates the voltage-controlled exchange interaction between electrons, qubit coherence times increase by an order of magnitude. Using randomized benchmarking, we measure single-qubit gate fidelities of  $\sim 99\%$ , and through self-consistent quantum measurement, state, and process tomography, we measure an entangling gate fidelity of 90%. In the future, operating double quantum dot spin qubits with large gradients in nuclear-spin-free materials, such as Si, should enable a two-qubit gate fidelity surpassing the threshold for fault-tolerant quantum information processing.

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## INTRODUCTION

The quantum phase coherence of isolated spins in semiconductors<sup>1–7</sup> can persist for long times, reaching tens of milliseconds for electron spins<sup>8</sup> and tens of minutes for nuclear spins.<sup>9</sup> Such long coherence times enable single-qubit gate fidelities exceeding the threshold for fault-tolerant quantum computing<sup>8</sup> and make spins promising qubits. However, entangling spins is difficult because magnetic interactions between spins are weak. For electrons, this challenge can be met by exploiting the charge of the electron for electric-dipole<sup>10</sup> or gate-controlled exchange coupling<sup>2</sup> between spins. In these methods, however, the qubit energy depends on electric fields, and charge noise in the host material limits single-qubit coherence.<sup>11</sup> Charge noise also affects other qubit platforms. For example, heating due to charge noise is a limiting factor in the coherence of trapped ion qubits,<sup>12</sup> and the transmon superconducting qubit was designed to suppress noise from charge fluctuations in superconducting islands.<sup>13</sup> Strategies such as composite pulses,<sup>14, 15</sup> dynamical decoupling,<sup>11</sup> and sweet-spot operation<sup>16–18</sup> have been developed to mitigate the effects of charge noise.

In this work, we present a technique to suppress decoherence caused by charge noise. The key idea is to apply a large transverse qubit energy splitting that does not depend on electric fields and, therefore, suppresses the effects of charge fluctuations. We implement this scheme with two singlet-triplet qubits, each of which consists of two electrons in a double-quantum-dot.<sup>2</sup> In each qubit, the voltage-controlled exchange interaction  $J(\epsilon)$ , where  $\epsilon$  represents the gate voltage, splits the singlet  $|S\rangle = (|\uparrow\downarrow\rangle - |\downarrow\uparrow\rangle)/\sqrt{2}$  and triplet  $|T_0\rangle = (|\uparrow\downarrow\rangle + |\downarrow\uparrow\rangle)/\sqrt{2}$  states in energy,<sup>2</sup> where the left (right) arrow indicates the spin of the left (right)

electron. A magnetic gradient  $\Delta B_z$  between the two dots lifts the degeneracy between  $|\uparrow\downarrow\rangle$  and  $|\downarrow\uparrow\rangle$ . These two mechanisms enable universal quantum control of singlet-triplet qubits.<sup>19</sup> Until now, two-qubit gates for singlet-triplet qubits have operated with  $J(\epsilon) \gg \Delta B_z$ , and charge noise is the limiting factor in two-qubit gate fidelities.<sup>2, 10</sup> However, if  $\Delta B_z \gg J(\epsilon)$ , the total qubit energy splitting is  $\Omega(\epsilon) = \sqrt{\Delta B_z^2 + J(\epsilon)^2} \approx \Delta B_z + J(\epsilon)^2/2\Delta B_z$ , and the qubit sensitivity to charge noise  $\Omega'(\epsilon) = (J(\epsilon)/\Delta B_z)J'(\epsilon)$  is reduced by a factor of  $J(\epsilon)/\Delta B_z$ , effectively mitigating decoherence due to charge noise.

Intense magnetic field gradients in spin qubits can be created with micromagnets.<sup>6, 20, 21</sup> In GaAs quantum dots, strong magnetic gradients can also be generated via the hyperfine interaction between the electron and Ga and As nuclear spins in the semiconductor.<sup>19, 22–24</sup> Coherence times for qubit rotations around hyperfine gradients can approach one millisecond,<sup>25</sup> which is significantly longer than typical exchange coherence times.<sup>11</sup> Here, we show that when the magnetic gradient in a GaAs singlet-triplet qubit dominates the electrically controlled exchange interaction, coherence times increase by an order of magnitude. Through both standard and interleaved randomized benchmarking, we measure average single-qubit gate fidelities of  $\sim 99\%$ . At the same time, this approach maintains a large interaction between adjacent capacitively coupled qubits. We use self-consistent two-qubit state- and measurement tomography to measure a Bell state with a maximum fidelity of 93%. Full process tomography involving 256 tomographic measurements of the two-qubit operation yields an entangling gate fidelity of 90%, consistent with theoretical simulations. In materials without

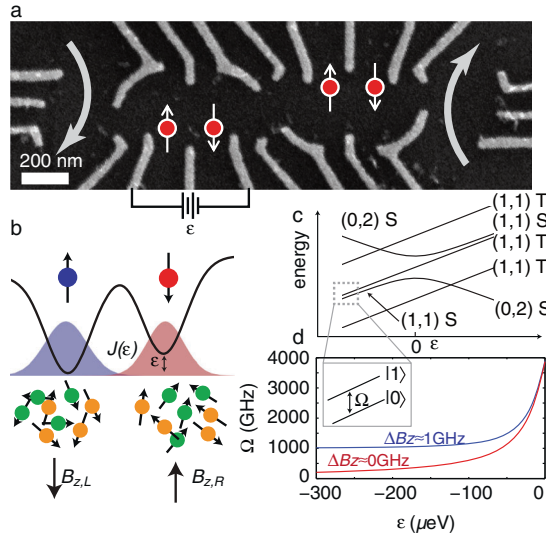
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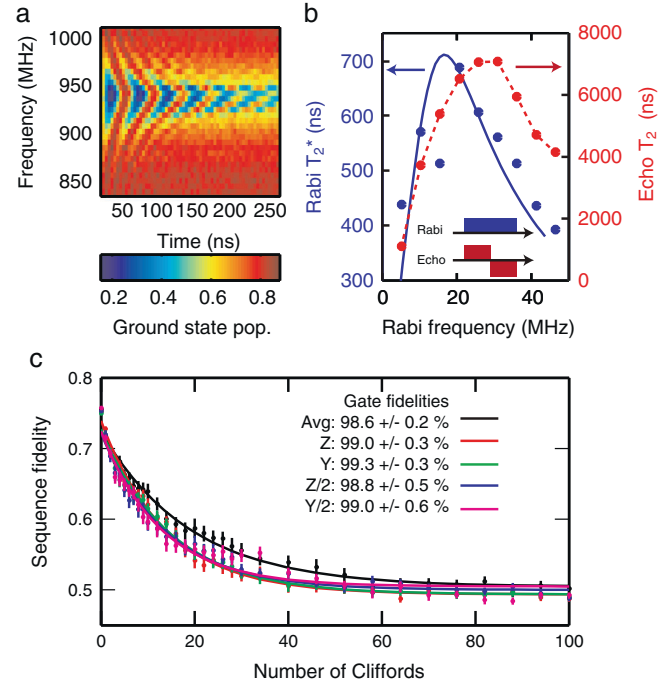
**Fig. 1** Experimental set-up. **a** Scanning electron micrograph of a two-qubit device identical to the one used in this work. Red circles indicate approximate positions of electrons in the double-well potentials created by metal depletion gates (gray). Arrows indicate the positions of sensor quantum dots. A voltage difference  $\epsilon$  applied to plunger gates adjusts the exchange interaction. **b** The gate-controlled wavefunction overlap between electron spins produces the exchange interaction  $J(\epsilon)$ . Each electron also interacts with a large number of Ga and As nuclear spins (green and orange circles) via the hyperfine interaction, leading to a difference in the longitudinal magnetic gradient between the dots  $\Delta B_z = B_{z,L} - B_{z,R}$ . **c** Energy level diagram showing the two-electron spin states of a double quantum dot. We operate the qubit with  $\epsilon < 0$  and  $J(\epsilon) \ll \Delta B_z$ , as indicated with the dashed gray box. **d** Calculated qubit energy splitting  $J(\epsilon)$  for the two cases when  $\Delta B_z = 0$  and  $\Delta B_z \approx 1$  GHz. When  $\Delta B_z$  is large, the qubit splitting does not depend on  $\epsilon$  and is insensitive to electric fields

nuclear spins such as silicon, even higher gate fidelities would be possible.

We use two singlet-triplet qubits,<sup>2</sup> created in gate-defined double quantum dots similar to those of refs (10, 11) in a GaAs/AlGaAs heterostructure (Fig. 1a). Each double quantum dot contains two electrons. The Hamiltonian for each qubit is  $H(\epsilon) = J(\epsilon)\sigma_z + \Delta B_z\sigma_x$ , in the  $\{|S\rangle, |T_0\rangle\}$  basis.  $J(\epsilon)$ , the exchange interaction between the two spins, depends on  $\epsilon$ , the difference in electrochemical potential between the dots (Fig. 1b).  $\Delta B_z$ , the difference in longitudinal magnetic field between the two dots, results from the wavefunction overlap between each electron and the Ga and As nuclear spins in the heterostructure. Although the nuclear spins are unpolarized in thermal equilibrium,  $\Delta B_z$  can be measured and stabilized up to several hundred mT using feedback.<sup>19, 22, 23</sup>

The two adjacent qubits are capacitively coupled, and the interaction Hamiltonian  $H_{int} = J_{12}\sigma_z \otimes \sigma_z$ , where  $J_{12} \propto J_1(\epsilon_1)J_2(\epsilon_2)$ ,<sup>10, 26</sup> and the subscripts refer to the different qubits. For the values of  $\epsilon$  used here, we empirically find that  $J'(\epsilon) \propto J(\epsilon)$ . This requires that  $J(\epsilon) > 0$  to maintain nonzero interqubit coupling.

Figure 1c shows the energy level diagram of the two-electron spin states in a double quantum dot. The qubit states are the  $|S\rangle$  and  $|T_0\rangle$  levels in the regime where  $\Delta B_z \gg J(\epsilon)$  (Fig. 1c, d). Through dynamic nuclear polarization and feedback, we set  $g^* \mu_B \Delta B_z / h \approx 1$  GHz in all experiments.<sup>19, 22</sup> Here,  $g^* = -0.44$  is the effective electron g-factor in GaAs,  $\mu_B$  is the Bohr magneton, and  $h$  is Planck's constant.  $\Delta B_z$  is stabilized to within 3 MHz, corresponding to an inhomogeneously broadened coherence time  $T_2^* \approx 100$  ns. We initialize the  $|0\rangle$  state through electron exchange with the



**Fig. 2** Single-qubit operations. **a** Time-varying voltage pulses resonant with the qubit splitting induce Rabi oscillations. **b** Coherence times of driven Rabi oscillations (blue) and rotary echo (red) vs. Rabi drive strength. The solid blue line is a theoretical curve taking into account the measured charge and hyperfine noise levels in our qubit. The data agree with the model. The dashed red line between data points is a guide to the eye. At low drive strengths, hyperfine fluctuations limit the coherence time, and at large drive strengths, charge-noise-induced fluctuations in the Rabi frequency limit the coherence. **c** Randomized benchmarking yields an average gate fidelity of  $98.6 \pm 0.2\%$ . Error bars are statistical uncertainties. Note that the qubit splitting points along the  $x$  direction, and all gates are performed with phase-modulated rf pulses. See Supplementary Information for more details on randomized benchmarking

leads when  $\epsilon \gg 0$ , where  $|S\rangle$  is the ground state of the double dot. Then we adiabatically ramp to  $\epsilon = \epsilon_0 < 0$ , where  $100 \text{ MHz} < J(\epsilon_0) / 2\pi < 300 \text{ MHz} < \Delta B_z$ . We measure the qubit state via electron exchange with the leads in a new technique (see Supplementary Information), which is compatible with large magnetic gradients.<sup>27</sup>

We drive qubit rotations by adding an oscillating voltage to the plunger gates, such that the total voltage  $\epsilon(t) = \epsilon_0 + \epsilon_1 \cos(\Omega t)$ . For  $\epsilon_1 \ll \epsilon_0$ ,  $J(t) \approx J(\epsilon_0) + 2j \cos(\Omega t)$ , where  $j = \frac{\epsilon_1}{2} J'(\epsilon_0)$  is the Rabi frequency. When the oscillation frequency matches the total qubit splitting  $\Omega = \sqrt{\Delta B_z^2 + J^2(\epsilon_0)}$ , the time varying component of  $J(t)$  drives qubit transitions (Fig. 2a).<sup>23</sup> In this regime,  $\Delta B_z$  is analogous to the external magnetic field for a single spin-1/2, while the time varying component of  $J(t)$  is analogous to a perpendicular oscillating magnetic field, which drives transitions. We emphasize that when  $\Delta B_z \gg J(\epsilon_0)$ ,  $\Omega(\epsilon_0) \approx \Delta B_z + \frac{J(\epsilon_0)^2}{2\Delta B_z}$ , and the sensitivity to charge noise  $\Omega'(\epsilon_0) = \frac{J(\epsilon_0)}{\Delta B_z} J'(\epsilon_0)$  is smaller by a factor of  $\frac{J(\epsilon_0)}{\Delta B_z}$  compared to the case where  $\Delta B_z \ll J(\epsilon_0)$  (Fig. 1d). However, a key requirement of this technique is that  $J(\epsilon_0) > 0$ , in order to maintain  $J'(\epsilon_0) > 0$  for single-qubit control and two-qubit coupling.

Large magnetic gradients can, therefore, completely suppress dephasing due to charge noise, although relaxation caused by charge noise at the qubit frequency  $\Delta B_z$  still limits the coherence. In our case, however, nuclear spin noise causes the magnetic gradient to fluctuate. To suppress the effects of hyperfine fluctuations, we apply a strong rf drive to the qubit, causing Rabi

oscillations. In the reference frame rotating around the qubit splitting  $\sigma_x$ , the Hamiltonian is  $H_{\text{rot}} = j\sigma_z + \delta\Omega\sigma_x$ , where  $j$  is the Rabi frequency, and  $\delta\Omega$  is a fluctuation in the magnetic gradient. When  $j \gg \delta$ , the qubit splitting in the rotating frame  $\Omega_{\text{rot}} \approx j + \frac{\delta\Omega^2}{2j}$  is first-order insensitive to fluctuations in the magnetic gradient.

## RESULTS

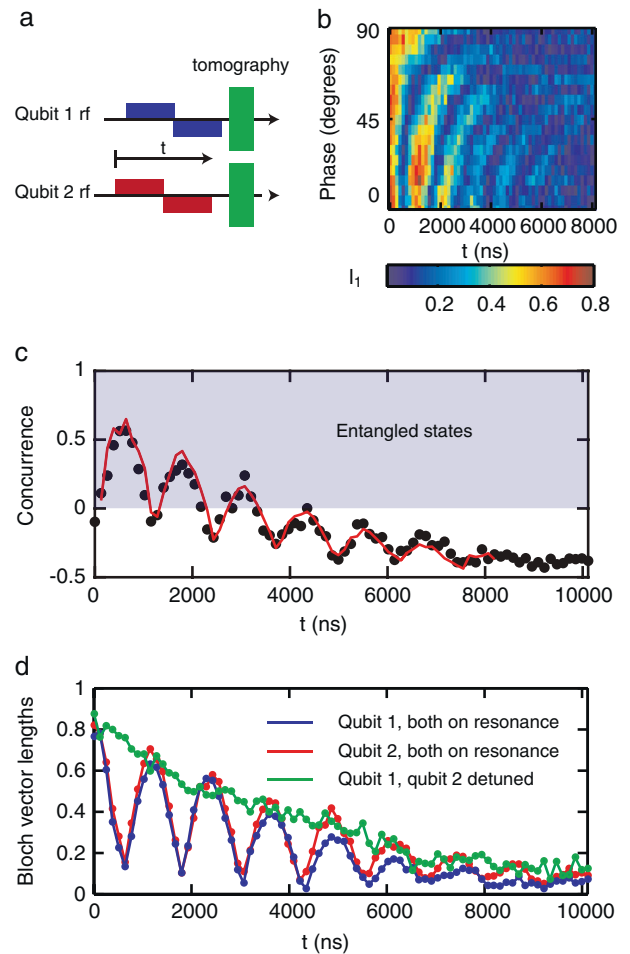
Figure 2b shows the coherence time of driven Rabi oscillations as a function of drive strength for  $J(\varepsilon_0)/(2\pi) = 220$  MHz. The maximum coherence time ( $\approx 700$  ns) is an order of magnitude larger than that for oscillations around a static exchange splitting with the same  $J(\varepsilon_0)$  ( $\approx 80$  ns). However, the quality factor of Rabi oscillations is the same as for static exchange oscillations,<sup>11</sup> because low-frequency charge noise limits the coherence time in both cases. But because  $j \ll J(\varepsilon_0)$ , the Rabi coherence time is much longer. It is this improvement in coherence that allows increased two-qubit gate fidelities, as described below. Reversing the phase of the drive halfway through the evolution to perform a rotary echo extends the coherence time by an additional factor of 10 (Fig. 2b). Rotating-frame echo coherence times are also an order of magnitude longer than static exchange echo<sup>11</sup> dephasing times measured in this device. We do not observe a large increase in coherence with multi-pulse dynamical decoupling, perhaps due to high-frequency charge noise.<sup>11</sup>

As the amplitude of the oscillating voltage  $\varepsilon_1$  increases, both the Rabi and echo coherence times reach a maximum (Fig. 2b). At low drive strengths, hyperfine fluctuations in the detuning limit the coherence. At large drive strengths, charge-noise-induced fluctuations in  $J(\varepsilon)$ , which cause the Rabi rates to fluctuate in time, limit the coherence. The observed behavior agrees well with a theoretical simulation based on measured noise levels in our qubit (Fig. 2b) (see Supplementary Information). The simulation correctly predicts the maximum coherence time and corresponding Rabi frequency. Using randomized benchmarking,<sup>28–34</sup> we find an average gate fidelity of  $98.6 \pm 0.2\%$ , with individual gate fidelities close to the average (Fig. 2c). (See the Supplementary Information for further experimental details on randomized benchmarking). Gate fidelities are likely coherence limited as a result of slow electric-field or hyperfine fluctuations. Given the observed quality factor of Rabi oscillations, which is  $\sim 5$ , (Fig. 2a), we would expect roughly 10 coherent  $\pi$  rotations within the coherence time. Assuming Gaussian decay due to low-frequency noise, the fidelity of a  $\pi$ -gate should be approximately  $e^{-(1/10)^2} = 0.99$ . Because hyperfine or charge fluctuations are slow compared with gate times ( $\approx 20$  ns), errors are likely correlated,<sup>35</sup> as is the case for most spin qubits. Suppressed low-frequency charge noise or composite pulses<sup>14, 15</sup> would improve gate fidelities.

Next, we take advantage of the long coherence times in the  $\Delta B_z$ -dominated regime to perform a high-fidelity two-qubit entangling gate. In the lab frame,  $H \approx \Omega_1 \sigma_x \otimes I + \Omega_2 I \otimes \sigma_x + J_{12} \sigma_z \otimes \sigma_z$ , where  $I$  is the identity operator. The single-qubit terms in the Hamiltonian do not commute with the interaction term, and the single-qubit rotations cancel the interaction except when  $\Omega_1 = \Omega_2$  (see Supplementary Information), in a manner analogous to the Hartmann-Hahn condition for nuclear double resonance.<sup>36</sup> In this case, the interaction in the rotating frame is

$$H_{\text{int}} \approx \frac{J_{12}}{2} \sigma_z \otimes \sigma_z \cos(\phi_1 - \phi_2). \quad (1)$$

Here  $J_{12} \propto J'_1(\varepsilon_1)J'_2(\varepsilon_2)$  is the interaction energy, and  $\phi_i$  is the phase of the rf drive on each qubit. When  $\Omega_1 = \Omega_2$  and  $\phi_1 = \phi_2$ , the single-qubit rotations constructively interfere, and the interaction is the same as in the lab frame, up to a factor of 1/2. The order-of-magnitude increase in single-qubit coherence discussed above, therefore, enables a substantially improved two-qubit gate fidelity. This interaction generates an operation equivalent to a controlled phase gate up to single-qubit rotations.



**Fig. 3** Entangling gate. **a** To entangle the qubits, we perform a simultaneous rotary echo on both for a varying total length of time  $t$ , followed by tomographic readout to reconstruct the two-qubit density matrix. **b** Bloch vector length for qubit 1,  $I_1$ , during the entangling gate as the phase between rf drives varies. Nodes in  $I_1$  denote entanglement. The entanglement rate vanishes when the qubits are driven  $90^\circ$  out of phase. **c** Concurrence vs. time for the entangling gate. Positive values of concurrence indicate entangled states. Negative values of concurrence indicate decoherence. The solid red line is a theoretical simulation taking into account hyperfine and low- and high-frequency charge noise (see Supplementary Information). **d** Single-qubit Bloch vector lengths  $I_1$  and  $I_2$  during joint evolution. When the qubits are detuned from each other, the interaction vanishes

To entangle the qubits, we set  $\Omega_1 = \Omega_2 = 960$  MHz and perform a simultaneous rotary echo for varying lengths of time (Fig. 3a), choosing the drive amplitude that maximizes the echo coherence time. Self-consistent two-qubit measurement and state tomography<sup>37</sup> (see Supplementary Information) reveal an oscillating concurrence of the two-qubit state (Fig. 3c). The concurrence is defined as  $C = \lambda_4 - \lambda_3 - \lambda_2 - \lambda_1$ , where the  $\lambda_i$  are eigenvalues of the two-qubit density matrix, arranged from smallest to largest.<sup>38</sup> The concurrence ranges from 1 to  $-0.5$ . A value of 0 indicates no entanglement between the qubits, a value of 1 indicates maximal entanglement, and a value of  $-0.5$  indicates complete dephasing. The observed concurrence periodically reaches values above zero, demonstrating repeated entangling and disentangling of the qubits as the interaction time increases. Eventually, the concurrence saturates at a negative value, because both qubits have dephased. We have performed numerical simulations taking into

account hyperfine noise and both low- and high-frequency charge noise (see Supplementary Information). The measured concurrence agrees with the simulation (Fig. 3c). As the concurrence reaches a local maximum, the length of the single-qubit Bloch

vectors,  $l = \sqrt{\langle \sigma_x \rangle^2 + \langle \sigma_y \rangle^2 + \langle \sigma_z \rangle^2}$ , where  $\langle \dots \rangle$  indicates a single-qubit expectation value, approach zero, as expected for entangled states (Fig. 3d).

As equation (1) suggests, the interaction strength depends on the relative phase between the rf drives on each qubit. We demonstrate phase control of the two-qubit interaction by measuring the length of the Bloch vector of one qubit as we vary the relative phase between qubits (Fig. 3b). As expected, the entangling rate reaches a maximum when the two qubits are driven in phase, and the entangling rate vanishes when the two qubits are out of phase.

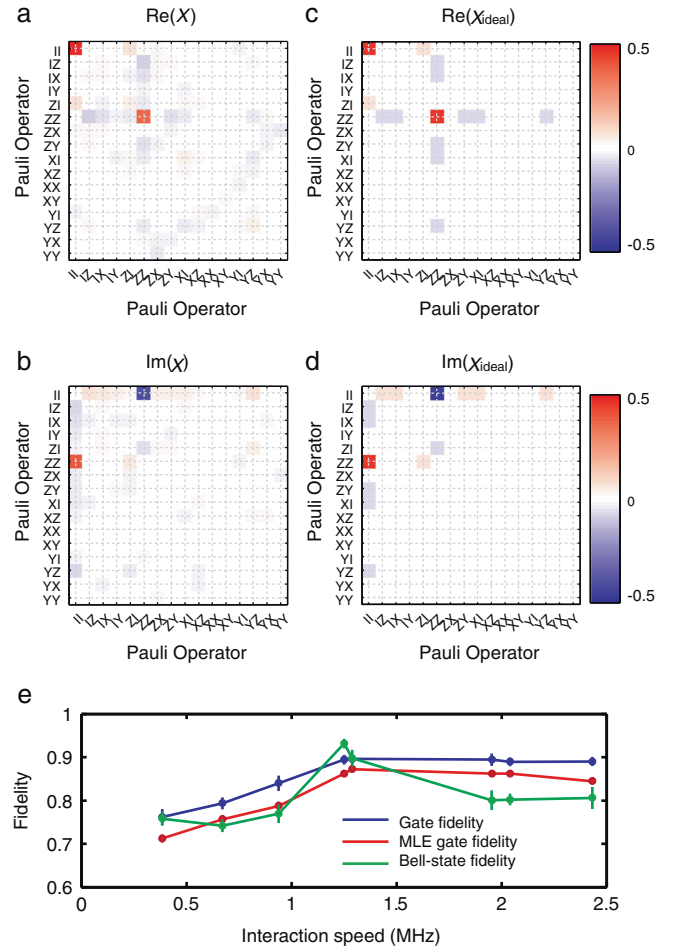
The two-qubit interaction also vanishes if  $\Omega_1 \neq \Omega_2$ . To demonstrate frequency control of the two-qubit gate, we turn off the dynamic nuclear polarization<sup>19</sup> on qubit 2, effectively setting  $\Omega_2 \approx 0$  MHz. However, all gate voltages during the entangling operation remain the same. Measuring the Bloch vector length of qubit 1 as a function of evolution time shows no oscillations, just a smooth decay (Fig. 3d). This indicates that no entanglement takes place, and hence that the interaction vanishes, when the two qubits are detuned from each other.

To assess the gate fidelity, we perform self-consistent quantum process tomography<sup>37, 39, 40</sup> on the two-qubit gate (Fig. 4a–d), requiring 256 tomographic measurements of the two-qubit operation. We extract a maximum gate fidelity of  $90 \pm 1\%$  based on a measured tomographically complete set of input and output states (see Supplementary Information). The extracted process matrix  $\chi$  has a few negative eigenvalues, which may result from partially mixed input states. Using a maximum likelihood estimation process to ensure a completely positive process matrix (see Supplementary Information), we extract a gate fidelity of  $87 \pm 1\%$ , which is consistent with the fidelity obtained by direct inversion.

Figure 4e shows the maximum observed gate and Bell state fidelity as a function of interaction strength, which is varied by adjusting  $J(\epsilon_0)$  on each qubit. Similar to the case of single qubit coherence times, the gate fidelity drops at low interaction rates due to hyperfine noise. Gate fidelities are also expected to drop at fast interaction times due to charge noise, but we did not perform this experiment because our dynamic nuclear polarization feedback is not stable in this regime. An additional source of error at large interaction strengths is relaxation of the qubit states during initialization due to increased charge noise. We observe a maximum concurrence of  $0.86 \pm 0.02$ , corresponding to a Bell state fidelity of  $93 \pm 1\%$ . Given that the observed Bell state fidelities are equal to or slightly larger than the gate fidelities, it is likely that both decoherence and control errors play a role in overall gate fidelity.

## DISCUSSION

The maximum entangled state fidelity presented here represents a reduction in infidelity of about a factor of 4 over the previous entangling gate between singlet-triplet qubits,<sup>10</sup> because the effects of charge noise are reduced when the magnetic gradient dominates the exchange interaction. This gate can be improved in the future by narrowing the hyperfine distribution<sup>41</sup> through rapid Hamiltonian estimation,<sup>23</sup> or by using spin qubits in nuclear-spin-free materials such as Si, where strong gradients can be established with micromagnets. We estimate that with laboratory frame coherence times of  $1 \mu\text{s}$  (instead of  $\approx 100$  ns here), rotating frame coherence times could increase by as much as 3–4 times. Longer coherence times such as these suggest that two-qubit



**Fig. 4** Process tomography for the two-qubit entangling gate. **a** Real component of the measured process matrix. **b** Imaginary component of the measured process matrix. **c** Real component of the ideal process matrix. **d** Imaginary component of the ideal process matrix. **e** Gate fidelity of the measured process matrix and most-likely completely positive process matrix and two-qubit Bell state fidelity as a function of interaction strength. Error bars are statistical errors

gate fidelities exceeding 99%, and fault-tolerant quantum computation using spins, are within reach.

## MATERIALS AND METHODS

The two double quantum dots are fabricated on a GaAs/AlGaAs heterostructure with a two-dimensional electron gas located 91 nm below the surface. The two-dimensional electron gas density  $n = 1.5 \times 10^{11} \text{ cm}^{-2}$  and mobility  $\mu = 2.5 \times 10^6 \text{ cm}^2 \text{ V}^{-1} \text{ s}^{-1}$  were measured at  $T = 4\text{K}$ . Voltages applied to Au/Pd depletion gates define the double-dot potential. The qubits are cooled in a dilution refrigerator to a base temperature of  $\sim 20 \text{ mK}$ . An external magnetic field  $B = 0.7 \text{ T}$  is applied in the plane of the semiconductor surface perpendicular to the axis of the double quantum dots. This orientation of the magnetic field ensures effective dynamic nuclear polarization.<sup>24</sup>

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## AUTHOR CONTRIBUTIONS

S.F., G.C.G., and M.J.M. grew and characterized the AlGaAs/GaAs heterostructure. S.P.H. fabricated the device. J.M.N. and L.A.O. performed the experiments. All authors discussed and analyzed the data and wrote the manuscript. A.Y. supervised the project.

## COMPETING INTERESTS

The authors declare no conflict of interest.

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